



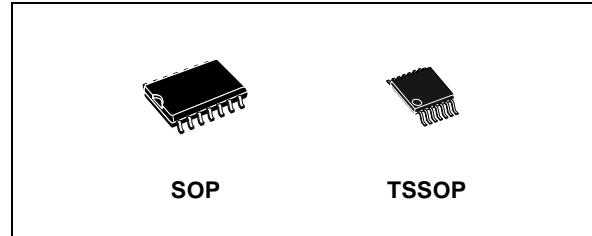
**74LCX07**

## LOW VOLTAGE CMOS HEX BUFFER (OPEN DRAIN) WITH 5V TOLERANT INPUTS

- 5V TOLERANT INPUTS
- HIGH SPEED:  
 $t_{PD} = 5.2\text{ns}$  (MAX.) at  $V_{CC} = 3\text{V}$
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OHI}| = I_{OL} = 24\text{mA}$  (MIN) at  $V_{CC} = 3\text{V}$
- PCI BUS LEVELS GUARANTEED AT 24 mA
- OPERATING VOLTAGE RANGE:  
 $V_{CC}(\text{OPR}) = 2.0\text{V}$  to  $3.6\text{V}$  (1.5V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 07
- LATCH-UP PERFORMANCE EXCEEDS 500mA (JESD 17)
- ESD PERFORMANCE:  
HBM > 2000V (MIL STD 883 method 3015); MM > 200V

### DESCRIPTION

The 74LCX07 is a low voltage CMOS OPEN DRAIN HEX BUFFER fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology. It is ideal for low power and high speed 3.3V applications. It can be interfaced to 5V signal environment for inputs.



**Table 1: Order Codes**

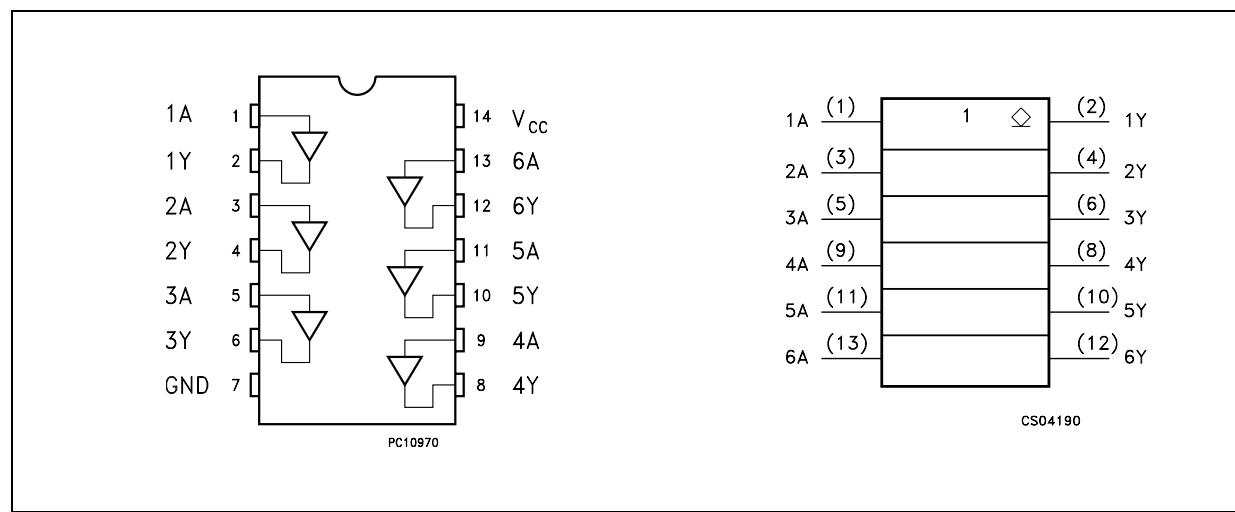
PACKAGE	T & R
SOP	74LCX07MTR
TSSOP	74LCX07TTR

The internal circuit is composed of 2 stages including buffer output, which provides high noise immunity and stable output.

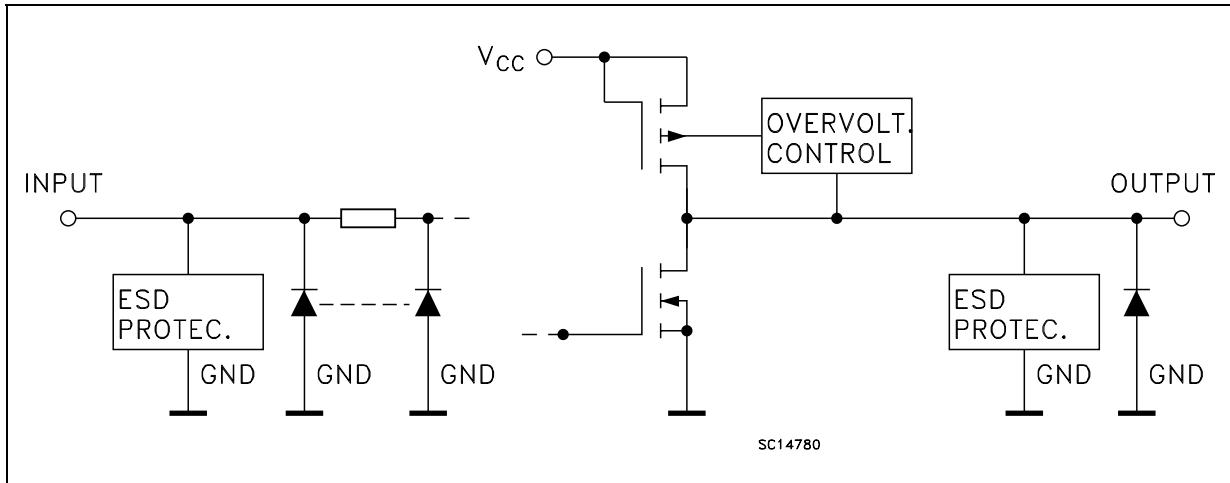
It has same speed performance at 3.3V than 5V AC/ACT family, combined with a lower power consumption.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

**Figure 1: Pin Connection And IEC Logic Symbols**



**Figure 2: Input And Output Equivalent Circuit**



**Table 2: Pin Description**

PIN N°	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A to 6A	Data Inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data Outputs
7	GND	Ground (0V)
14	$V_{CC}$	Positive Supply Voltage

**Table 3: Truth Table**

A	Y
L	L
H	Z

Z : High Impedance

**Table 4: Absolute Maximum Ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to +7.0	V
$V_I$	DC Input Voltage	-0.5 to +7.0	V
$V_O$	DC Output Voltage ( $V_{CC} = 0V$ )	-0.5 to +7.0	V
$V_O$	DC Output Voltage (High or Low State) (note 1)	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	-50	mA
$I_{OK}$	DC Output Diode Current (note 2)	-50	mA
$I_O$	DC Output Current	$\pm 50$	mA
$I_{CC}$	DC Supply Current per Supply Pin	$\pm 100$	mA
$I_{GND}$	DC Ground Current per Supply Pin	$\pm 100$	mA
$T_{stg}$	Storage Temperature	-65 to +150	°C
$T_L$	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

- 1)  $I_O$  absolute maximum rating must be observed
- 2)  $V_O < GND$

**Table 5: Recommended Operating Conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage (note 1)	2.0 to 3.6	V
$V_I$	Input Voltage	0 to 5.5	V
$V_O$	Output Voltage ( $V_{CC} = 0V$ )	0 to 5.5	V
$V_O$	Output Voltage (High or Low State)	0 to $V_{CC}$	V
$I_{OH}, I_{OL}$	High or Low Level Output Current ( $V_{CC} = 3.0$ to 3.6V)	$\pm 24$	mA
$I_{OH}, I_{OL}$	High or Low Level Output Current ( $V_{CC} = 2.7V$ )	$\pm 12$	mA
$T_{op}$	Operating Temperature	-55 to 125	°C
$dt/dv$	Input Rise and Fall Time (note 2)	0 to 10	ns/V

1) Truth Table guaranteed: 1.5V to 3.6V

2)  $V_{IN}$  from 0.8V to 2V at  $V_{CC} = 3.0V$ **Table 6: DC Specifications**

Symbol	Parameter	Test Condition		Value				Unit	
		$V_{CC}$ (V)		-40 to 85 °C		-55 to 125 °C			
				Min.	Max.	Min.	Max.		
$V_{IH}$	High Level Input Voltage	2.7 to 3.6		2.0		2.0		V	
$V_{IL}$	Low Level Input Voltage				0.8		0.8	V	
$V_{OL}$	Low Level Output Voltage	2.7 to 3.6	$I_O=100 \mu A$		0.2		0.2	V	
		2.7	$I_O=12 mA$		0.4		0.4		
		3.0	$I_O=16 mA$		0.4		0.4		
			$I_O=24 mA$		0.55		0.55		
$I_I$	Input Leakage Current	2.7 to 3.6	$V_I = 0$ to 5.5V		$\pm 5$		$\pm 5$	$\mu A$	
$I_{off}$	Power Off Leakage Current	0	$V_I$ or $V_O = 5.5V$		10		10	$\mu A$	
$I_{OZ}$	High Impedance Output Leakage Current	2.7 to 3.6	$V_I = V_{IH}$ or $V_{IL}$ $V_O = 0$ to $V_{CC}$		$\pm 5$		$\pm 5$	$\mu A$	
$I_{CC}$	Quiescent Supply Current	2.7 to 3.6	$V_I = V_{CC}$ or GND		10		10	$\mu A$	
			$V_I$ or $V_O = 3.6$ to 5.5V		$\pm 10$		$\pm 10$		
$\Delta I_{CC}$	$I_{CC}$ incr. per Input	2.7 to 3.6	$V_{IH} = V_{CC} - 0.6V$		500		500	$\mu A$	

**Table 7: Dynamic Switching Characteristics**

Symbol	Parameter	Test Condition		Value			Unit	
		$V_{CC}$ (V)		$T_A = 25$ °C				
				Min.	Typ.	Max.		
$V_{OLP}$	Dynamic Low Level Quiet Output (note 1)	3.3	$V_{IL} = 0V$ $V_{IH} = 3.3V$		0.8		V	
					-0.8			

1) Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.

**Table 8: AC Electrical Characteristics**

Symbol	Parameter	Test Condition				Value				Unit	
		V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	R <sub>L</sub> (Ω)	t <sub>s</sub> = t <sub>r</sub> (ns)	-40 to 85 °C		-55 to 125 °C			
						Min.	Max.	Min.	Max.		
t <sub>PLZ</sub>	Propagation Delay Time	2.7	50	500	2.5		7.0		7.0	ns	
		3.0 to 3.6				1.0	5.2	1.0	5.2		
t <sub>PZL</sub>	Propagation Delay Time	2.7	50	500	2.5		7.0		7.0	ns	
		3.0 to 3.6				1.0	5.2	1.0	5.2		
t <sub>OSLH</sub> t <sub>OSSH</sub>	Output To Output Skew Time (note1, 2)	3.0 to 3.6	50	500	2.5		1.0		1.0	ns	

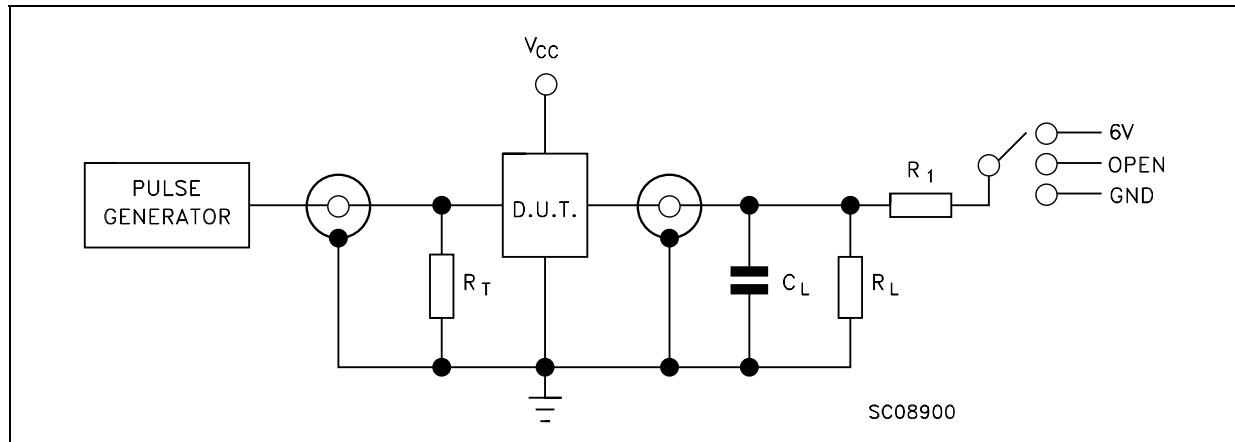
1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW ( $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$ ,  $t_{OSSH} = |t_{PHLm} - t_{PHLn}|$ )

2) Parameter guaranteed by design

**Table 9: Capacitive Characteristics**

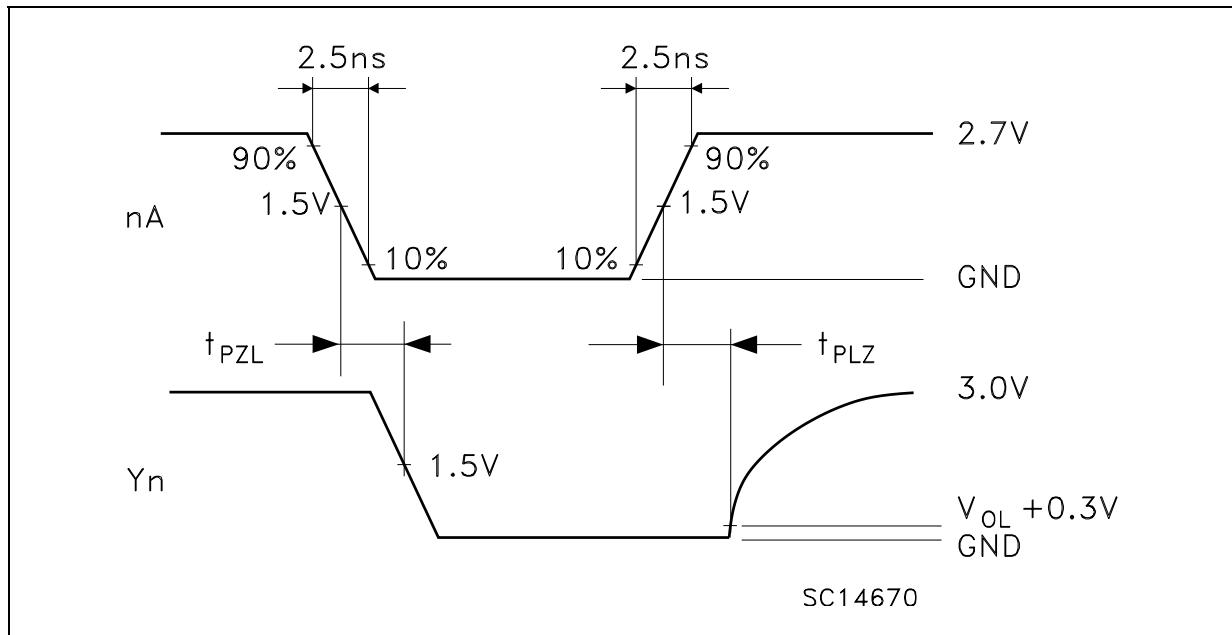
Symbol	Parameter	Test Condition		Value			Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C				
				Min.	Typ.	Max.		
C <sub>IN</sub>	Input Capacitance	3.3	V <sub>IN</sub> = 0 to V <sub>CC</sub>		6		pF	
C <sub>OUT</sub>	Output Capacitance	3.3	V <sub>IN</sub> = 0 to V <sub>CC</sub>		14		pF	
C <sub>PD</sub>	Power Dissipation Capacitance (note 1)	3.3	f <sub>IN</sub> = 10MHz V <sub>IN</sub> = 0 or V <sub>CC</sub>		4.3		pF	

1) C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I<sub>CC(opr)</sub> = C<sub>PD</sub> × V<sub>CC</sub> × f<sub>IN</sub> + I<sub>CC</sub>/6 (per gate)

**Figure 3: Test Circuit**

TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6V
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

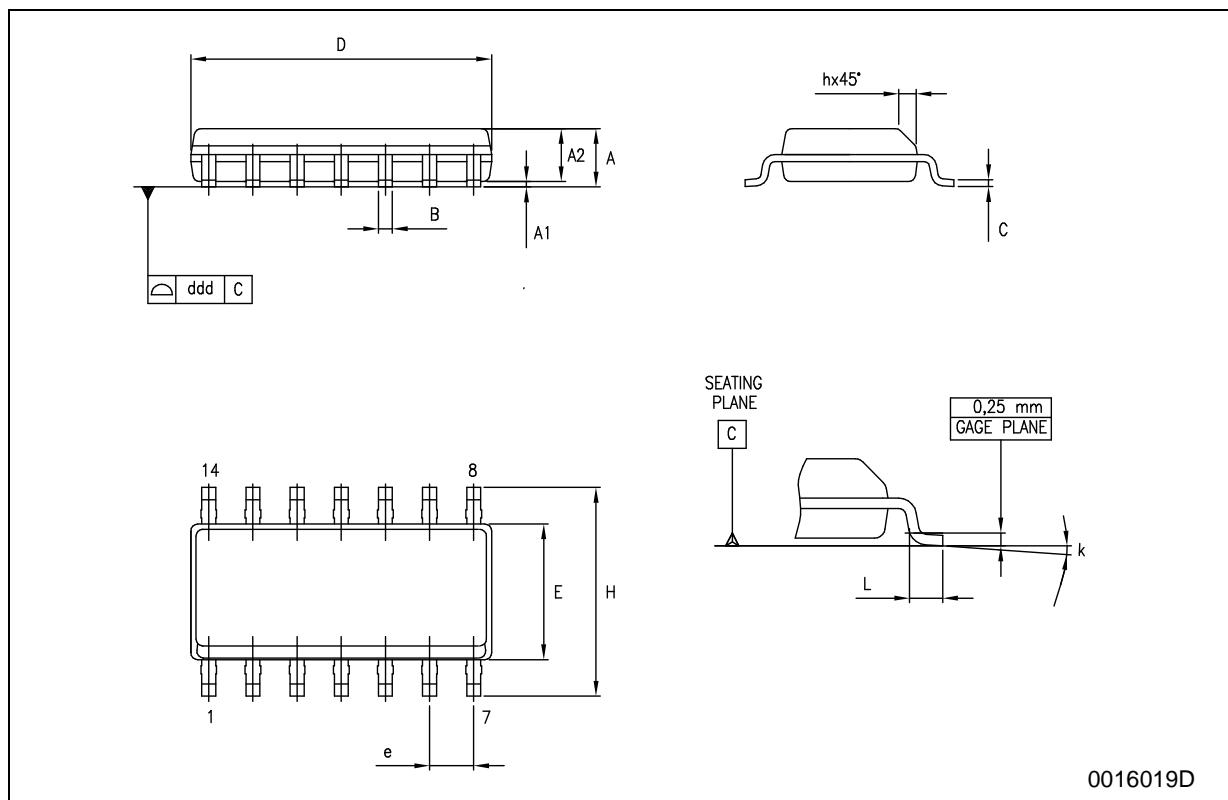
C<sub>L</sub> = 50 pF or equivalent (includes jig and probe capacitance)  
R<sub>L</sub> = R<sub>1</sub> = 500Ω or equivalent  
R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50Ω)

**Figure 4: Waveform - Propagation Delay (f=1MHz; 50% duty cycle)**

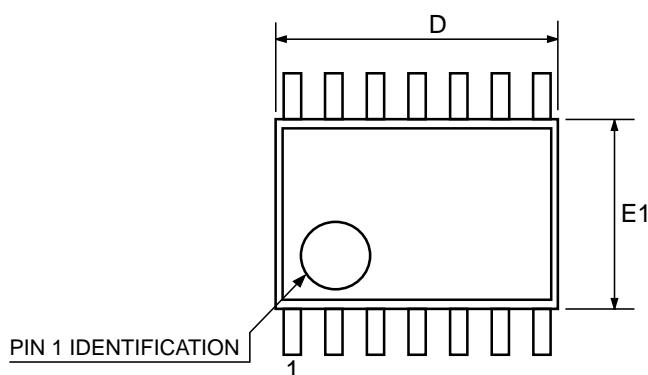
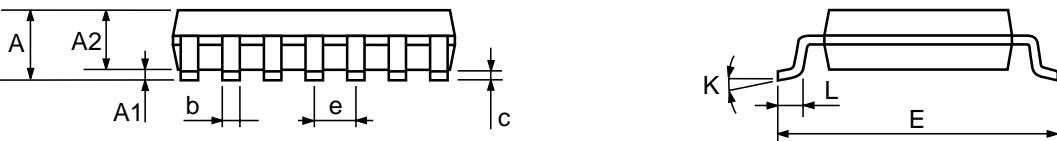
SC14670

## SO-14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.1		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D	8.55		8.75	0.337		0.344
E	3.8		4.0	0.150		0.157
e		1.27			0.050	
H	5.8		6.2	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.4		1.27	0.016		0.050
k	0°		8°	0°		8°
ddd			0.100			0.004

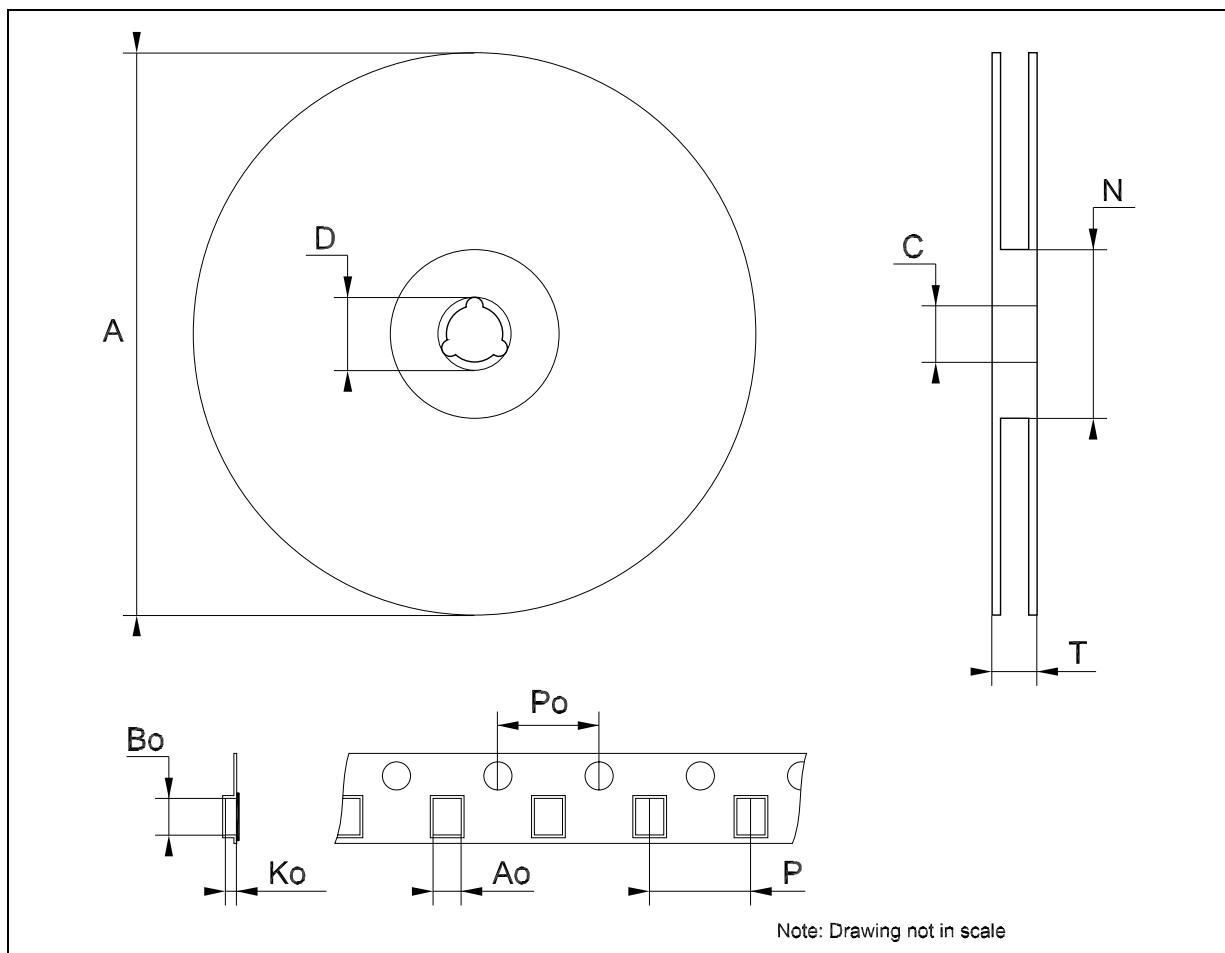


TSSOP14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

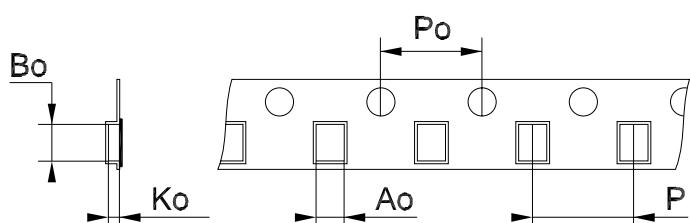
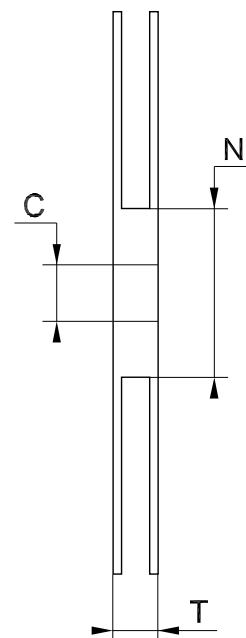
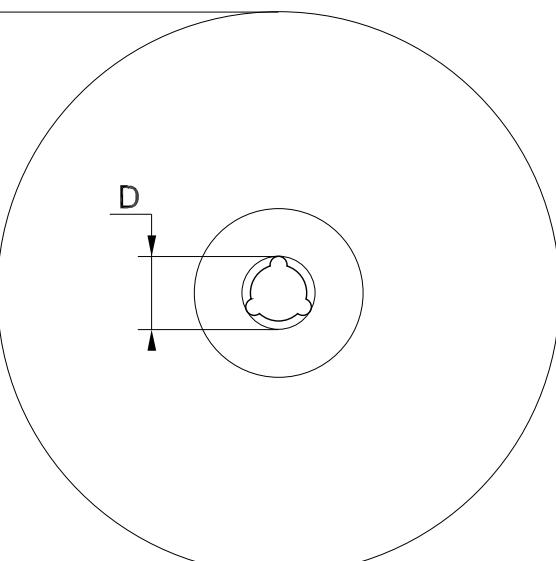


0080337D

Tape & Reel SO-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.4		6.6	0.252		0.260
Bo	9		9.2	0.354		0.362
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



Tape & Reel TSSOP14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Bo	5.3		5.5	0.209		0.217
Ko	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



Note: Drawing not in scale

**Table 10: Revision History**

Date	Revision	Description of Changes
15-Sep-2004	4	Ordering Codes Revision - pag. 1.

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